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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	516096
Number of I/O	147
Number of Gates	3000000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	208-BFQFP
Supplier Device Package	208-PQFP (28x28)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/a3pe3000-pq208

Temperature Grade Offerings

Package	A3PE600	A3PE1500	A3PE3000
Cortex-M1 Devices		**M1A3PE1500**	**M1A3PE3000**
PQ208	C, I	C, I	C, I
FG256	C, I	–	–
FG324	–	–	C, I
FG484	C, I	C, I	C, I
FG676	–	C, I	–
FG896	–	–	C, I

Note: C = Commercial temperature range: 0°C to 70°C ambient temperature
I = Industrial temperature range: –40°C to 85°C ambient temperature

Speed Grade and Temperature Grade Matrix

Temperature Grade	Std.	–1	–2
C [1]	✓	✓	✓
I [2]	✓	✓	✓

Notes:
1. *C = Commercial temperature range: 0°C to 70°C ambient temperature*
2. *I = Industrial temperature range: –40°C to 85°C ambient temperature*

References made to ProASIC3E devices also apply to ARM-enabled ProASIC3E devices. The ARM-enabled part numbers start with M1 (Cortex-M1).

Contact your local Microsemi SoC Products Group representative for device availability: *www.microsemi.com/index.php?option=com_content&id=135&lang=en&view=article*.

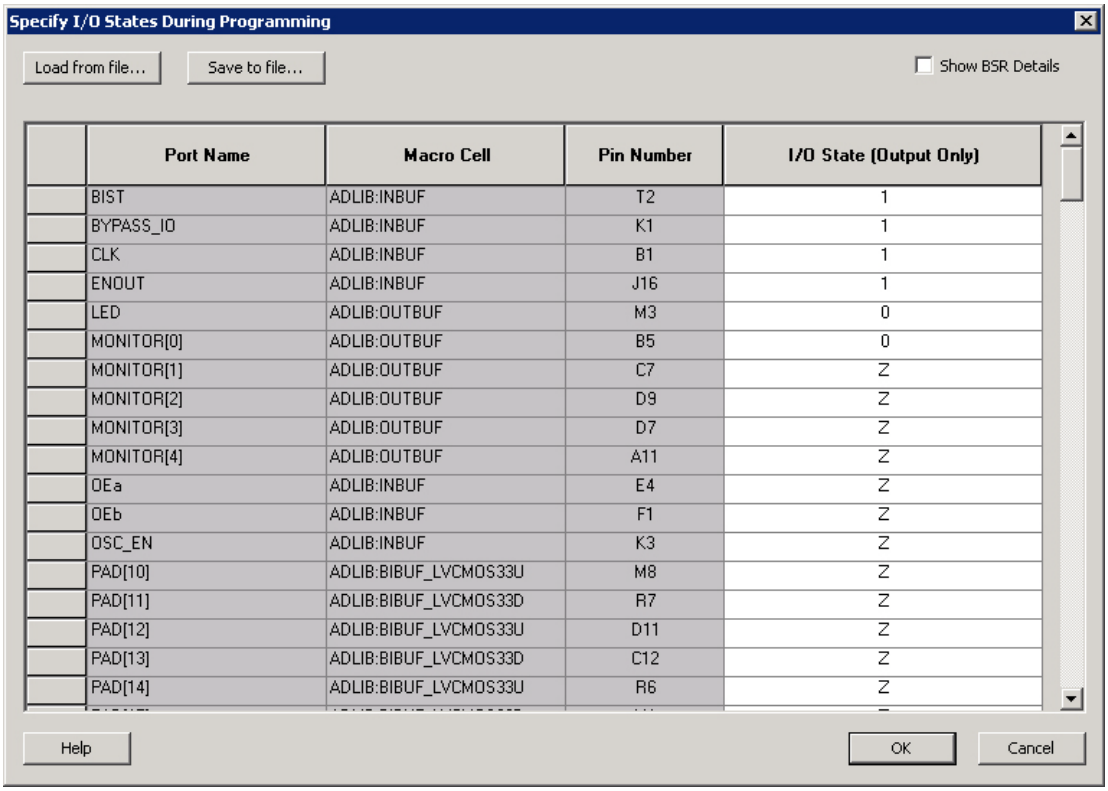


Figure 1-3 • **I/O States During Programming Window**

6. Click OK to return to the FlashPoint – Programming File Generator window.

   I/O States during programming are saved to the ADB and resulting programming files after completing programming file generation.

Table 2-17 • Summary of I/O Timing Characteristics—Software Default Settings –2 Speed Grade, Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V

I/O Standard	Drive Strength (mA)	Equivalent Software Default Drive Strength Option)[1]	Slew Rate	Capacitive Load (pF)	External Resistor (Ω)	t_{DOUT} (ns)	t_{DP} (ns)	t_{DIN} (ns)	t_{PY} (ns)	t_{PYS} (ns)	t_{EOUT} (ns)	t_{ZL} (ns)	t_{ZH} (ns)	t_{LZ} (ns)	t_{HZ} (ns)	t_{ZLS} (ns)	t_{ZHS} (ns)
3.3 V LVTTL / 3.3 V LVCMOS	12	12	High	35	–	0.49	2.74	0.03	0.90	1.17	0.32	2.79	2.14	2.45	2.70	4.46	3.81
3.3 V LVCMOS Wide Range[2]	100 µA	12	High	35	–	0.49	4.24	0.03	1.36	1.78	0.32	4.24	3.25	3.78	4.17	6.77	5.79
2.5 V LVCMOS	12	12	High	35	–	0.49	2.80	0.03	1.13	1.24	0.32	2.85	2.61	2.51	2.61	4.52	4.28
1.8 V LVCMOS	12	12	High	35	–	0.49	2.83	0.03	1.08	1.42	0.32	2.89	2.31	2.79	3.16	4.56	3.98
1.5 V LVCMOS	12	12	High	35	–	0.49	3.30	0.03	1.27	1.60	0.32	3.36	2.70	2.96	3.27	5.03	4.37
3.3 V PCI	Per PCI spec	–	High	10	25 [3]	0.49	2.09	0.03	0.78	1.17	0.32	2.13	1.49	2.45	2.70	3.80	3.16
3.3 V PCI-X	Per PCI-X spec	–	High	10	25[3]	0.49	2.09	0.03	0.78	1.17	0.32	2.13	1.49	2.45	2.70	3.80	3.16
3.3 V GTL	20 [4]	–	High	10	25	0.45	1.55	0.03	2.19	–	0.32	1.52	1.55	–	–	3.19	3.22
2.5 V GTL	20 [4]	–	High	10	25	0.45	1.59	0.03	1.83	–	0.32	1.61	1.59	–	–	3.28	3.26
3.3 V GTL+	35	–	High	10	25	0.45	1.53	0.03	1.19	–	0.32	1.56	1.53	–	–	3.23	3.20
2.5 V GTL+	33	–	High	10	25	0.45	1.65	0.03	1.13	–	0.32	1.68	1.57	–	–	3.35	3.24
HSTL (I)	8	–	High	20	50	0.49	2.37	0.03	1.59	–	0.32	2.42	2.35	–	–	4.09	4.02
HSTL (II)	15 [4]	–	High	20	25	0.49	2.26	0.03	1.59	–	0.32	2.30	2.03	–	–	3.97	3.70
SSTL2 (I)	15	–	High	30	50	0.49	1.59	0.03	1.00	–	0.32	1.62	1.38	–	–	3.29	3.05
SSTL2 (II)	18	–	High	30	25	0.49	1.62	0.03	1.00	–	0.32	1.65	1.32	–	–	3.32	2.99
SSTL3 (I)	14	–	High	30	50	0.49	1.72	0.03	0.93	–	0.32	1.75	1.37	–	–	3.42	3.04
SSTL3 (II)	21	–	High	30	25	0.49	1.54	0.03	0.93	–	0.32	1.57	1.25	–	–	3.24	2.92
LVDS/B-LVDS/ M-LVDS	24	–	High	–	–	0.49	1.40	0.03	1.36	–	–	–	–	–	–	–	–
LVPECL	24	–	High	–	–	0.49	1.36	0.03	1.22	–	–	–	–	–	–	–	–

Notes:

1. *The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 µA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.*
2. *All LVCMOS 3.3 V software macros support LVCMOS 3.3V wide range as specified in the JESD8b specification.*
3. *Resistance is used to measure I/O propagation delays as defined in PCI specifications. See Figure 2-11 on page 2-38 for connectivity. This resistor is not required during normal operation.*
4. *Output drive strength is below JEDEC specification.*
5. *For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5.*

Table 2-19 • I/O Output Buffer Maximum Resistances[1] (continued)

Standard	Drive Strength	$R_{PULL\text{-}DOWN}$ (Ω)[2]	$R_{PULL\text{-}UP}$ (Ω)[3]
3.3 V GTL+	35 mA	12	–
2.5 V GTL+	33 mA	15	–
HSTL (I)	8 mA	50	50
HSTL (II)	15 mA[4]	25	25
SSTL2 (I)	15 mA	27	31
SSTL2 (II)	18 mA	13	15
SSTL3 (I)	14 mA	44	69
SSTL3 (II)	21 mA	18	32

Notes:

1. *These maximum values are provided for informational reasons only. Minimum output buffer resistance values depend on VCCI, drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the Microsemi SoC Products Group website at www.microsemi.com/index.php?option=com_content&id=1671&lang=en&view=article.*
2. $R_{(PULL\text{-}DOWN\text{-}MAX)}$ = (VOLspec) / IOLspec
3. $R_{(PULL\text{-}UP\text{-}MAX)}$ = (VCCImax – VOHspec) / IOHspec
4. *Output drive strength is below JEDEC specification.*

Table 2-20 • I/O Weak Pull-Up/Pull-Down Resistances
Minimum and Maximum Weak Pull-Up/Pull-Down Resistance Values

	$R_{(WEAK\ PULL\text{-}UP)}$[1] (Ω)		$R_{(WEAK\ PULL\text{-}DOWN)}$[2] (Ω)	
VCCI	Min.	Max.	Min.	Max.
3.3 V	10 k	45 k	10 k	45 k
3.3 V (Wide Range I/Os)	10 k	45 k	10 k	45 k
2.5 V	11 k	55 k	12 k	74 k
1.8 V	18 k	70 k	17 k	110 k
1.5 V	19 k	90 k	19 k	140 k

Notes:

1. $R_{(WEAK\ PULL\text{-}UP\text{-}MAX)}$ = (VCCImax – VOHspec) / $I_{(WEAK\ PULL\text{-}UP\text{-}MIN)}$
2. $R_{(WEAK\ PULL\text{-}DOWN\text{-}MAX)}$ = (VOLspec) / $I_{(WEAK\ PULL\text{-}DOWN\text{-}MIN)}$

Timing Characteristics

Table 2-31 • 3.3 V LVCMOS Wide Range High Slew
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 2.7 V

Drive Strength	Equivalent Software Default Drive Strength Option[1]	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{PYS}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
100 µA	4 mA	Std.	0.66	12.19	0.04	1.83	2.38	0.43	12.19	10.17	4.16	4.00	15.58	13.57	ns
		–1	0.56	10.37	0.04	1.55	2.02	0.36	10.37	8.66	3.54	3.41	13.26	11.54	ns
		–2	0.49	9.10	0.03	1.36	1.78	0.32	9.10	7.60	3.11	2.99	11.64	10.13	ns
100 µA	8 mA	Std.	0.66	7.85	0.04	1.83	2.38	0.43	7.85	6.29	4.71	4.97	11.24	9.68	ns
		–1	0.56	6.68	0.04	1.55	2.02	0.36	6.68	5.35	4.01	4.22	9.57	8.24	ns
		–2	0.49	5.86	0.03	1.36	1.78	0.32	5.86	4.70	3.52	3.71	8.40	7.23	ns
100 µA	12 mA	Std.	0.66	5.67	0.04	1.83	2.38	0.43	5.67	4.36	5.06	5.59	9.07	7.75	ns
		–1	0.56	4.82	0.04	1.55	2.02	0.36	4.82	3.71	4.31	4.75	7.71	6.59	ns
		–2	0.49	4.24	0.03	1.36	1.78	0.32	4.24	3.25	3.78	4.17	6.77	5.79	ns
100 µA	16 mA	Std.	0.66	5.35	0.04	1.83	2.38	0.43	5.35	3.96	5.15	5.76	8.75	7.35	ns
		–1	0.56	4.55	0.04	1.55	2.02	0.36	4.55	3.36	4.38	4.90	7.44	6.25	ns
		–2	0.49	4.00	0.03	1.36	1.78	0.32	4.00	2.95	3.85	4.30	6.53	5.49	ns
100 µA	24 mA	Std.	0.66	4.96	0.04	1.83	2.38	0.43	4.96	3.27	5.23	6.38	8.35	6.67	ns
		–1	0.56	4.22	0.04	1.55	2.02	0.36	4.22	2.78	4.45	5.43	7.11	5.67	ns
		–2	0.49	3.70	0.03	1.36	1.78	0.32	3.70	2.44	3.91	4.76	6.24	4.98	ns

Notes:

1. *The minimum drive strength for any LVCMOS 3.3 V software configuration when run in wide range is ±100 µA. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.*
2. *Software default selection highlighted in gray.*
3. *For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.*

1.8 V LVCMOS

Low-Voltage CMOS for 1.8 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 1.8 V applications. It uses a 1.8 V input buffer and a push-pull output buffer.

Table 2-37 • Minimum and Maximum DC Input and Output Levels

1.8 V LVCMOS	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL[1]	IIH[2]
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA[3]	Max. mA[3]	µA[4]	µA[4]
2 mA	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	2	2	11	9	10	10
4 mA	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	4	4	22	17	10	10
6 mA	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	6	6	44	35	10	10
8 mA	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	8	8	51	45	10	10
12 mA	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	12	12	74	91	10	10
16 mA	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	16	16	74	91	10	10

Notes:

1. *IIL is the input leakage current per I/O pin over recommended operation conditions where –0.3 V < VIN < VIL.*
2. *IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.*
3. *Currents are measured at high temperature (100°C junction temperature) and maximum voltage.*
4. *Currents are measured at 85°C junction temperature.*
5. *Software default selection highlighted in gray.*

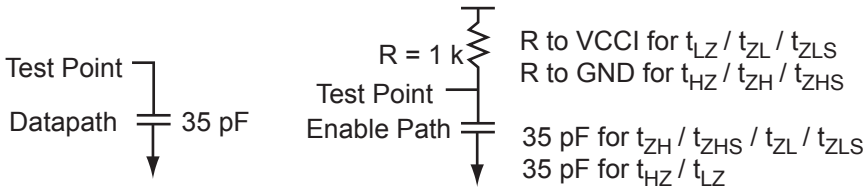


Figure 2-9 • AC Loading

Table 2-38 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	C_{LOAD} (pF)
0	1.8	0.9	–	35

*Note: *Measuring point = Vtrip. See Table 2-15 on page 2-18 for a complete table of trip points.*

2.5 V GTL

Gunning Transceiver Logic is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 2.5 V.

Table 2-51 • Minimum and Maximum DC Input and Output Levels

2.5 GTL	VIL		VIH		VOL	VOH	IOL	IOH	IOSL	IOSH	IIL	IIH
Drive Strength	Min., V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA[1]	Max. mA[1]	µA[2]	µA[2]
20 mA[3]	–0.3	VREF – 0.05	VREF + 0.05	3.6	0.4	–	20	20	124	169	10	10

Notes:

1. *Currents are measured at high temperature (100°C junction temperature) and maximum voltage.*
2. *Currents are measured at 85°C junction temperature.*
3. *Output drive strength is below JEDEC specification.*

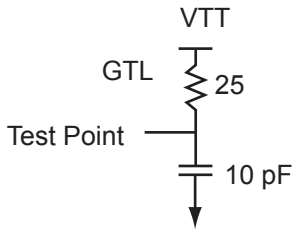


Figure 2-13 • AC Loading

Table 2-52 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C_{LOAD} (pF)
VREF – 0.05	VREF + 0.05	0.8	0.8	1.2	10

*Note: *Measuring point = Vtrip. See Table 2-15 on page 2-18 for a complete table of trip points.*

Timing Characteristics

Table 2-53 • 2.5 V GTL
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V VREF = 0.8 V

Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
Std.	0.60	2.13	0.04	2.46	0.43	2.16	2.13			4.40	4.36	ns
–1	0.51	1.81	0.04	2.09	0.36	1.84	1.81			3.74	3.71	ns
–2	0.45	1.59	0.03	1.83	0.32	1.61	1.59			3.28	3.26	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

Differential I/O Characteristics

Physical Implementation

Configuration of the I/O modules as a differential pair is handled by the Designer software when the user instantiates a differential I/O macro in the design.

Differential I/Os can also be used in conjunction with the embedded Input Register (InReg), Output Register (OutReg), Enable Register (EnReg), and DDR. However, there is no support for bidirectional I/Os or tristates with the LVPECL standards.

LVDS

Low-Voltage Differential Signaling (ANSI/TIA/EIA-644) is a high-speed, differential I/O standard. It requires that one data bit be carried through two signal lines, so two pins are needed. It also requires external resistor termination.

The full implementation of the LVDS transmitter and receiver is shown in an example in Figure 2-22. The building blocks of the LVDS transmitter-receiver are one transmitter macro, one receiver macro, three board resistors at the transmitter end, and one resistor at the receiver end. The values for the three driver resistors are different from those used in the LVPECL implementation because the output standard specifications are different.

Along with LVDS I/O, ProASIC3E also supports Bus LVDS structure and Multipoint LVDS (M-LVDS) configuration (up to 40 nodes).

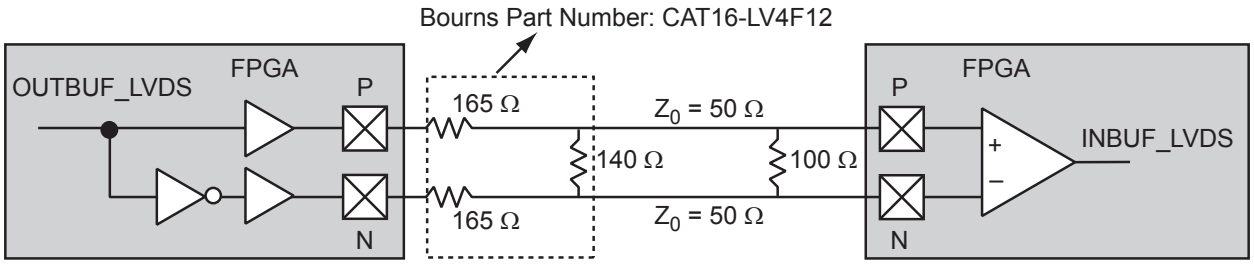


Figure 2-22 • **LVDS Circuit Diagram and Board-Level Implementation**

I/O Register Specifications

Fully Registered I/O Buffers with Synchronous Enable and Asynchronous Preset

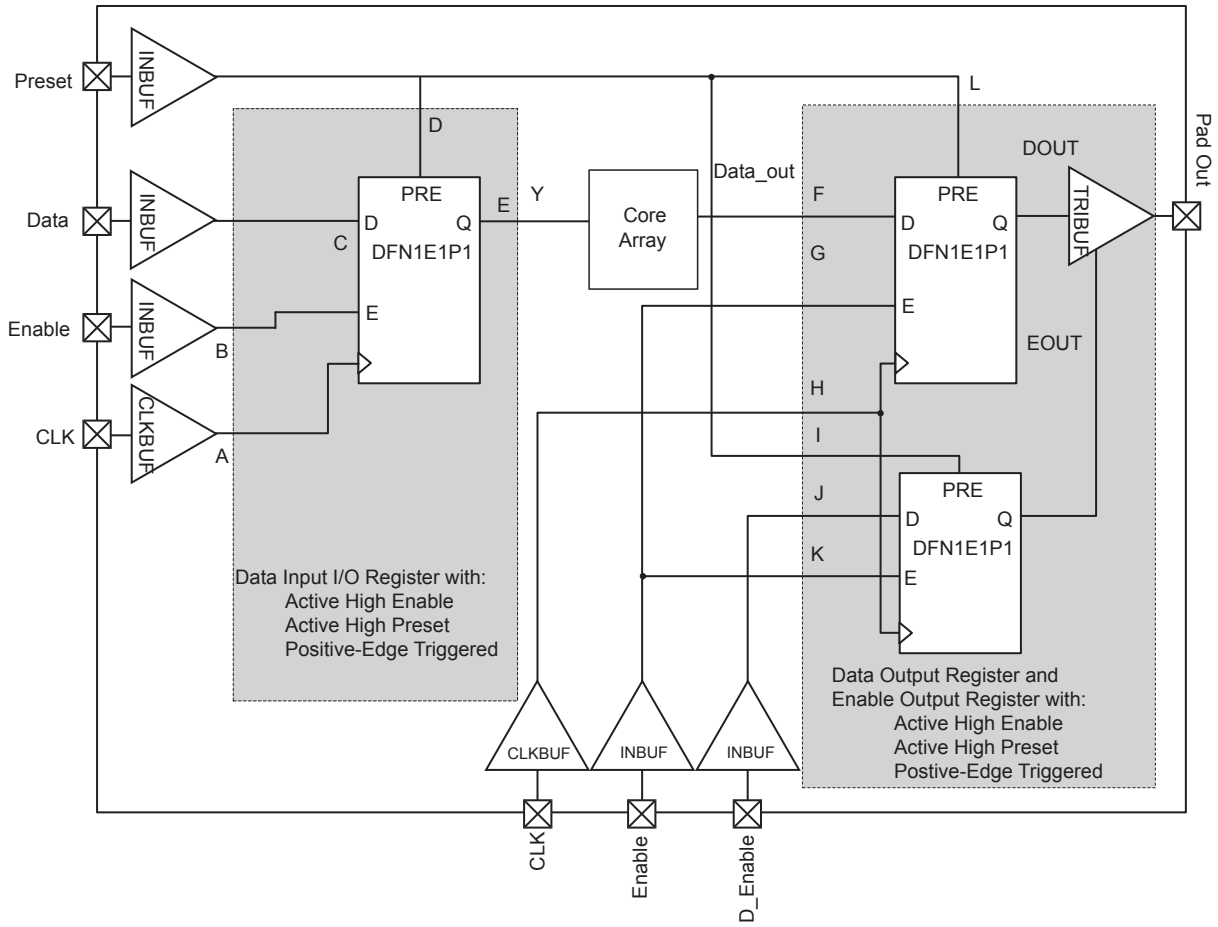


Figure 2-25 • **Timing Model of Registered I/O Buffers with Synchronous Enable and Asynchronous Preset**

Output Enable Register

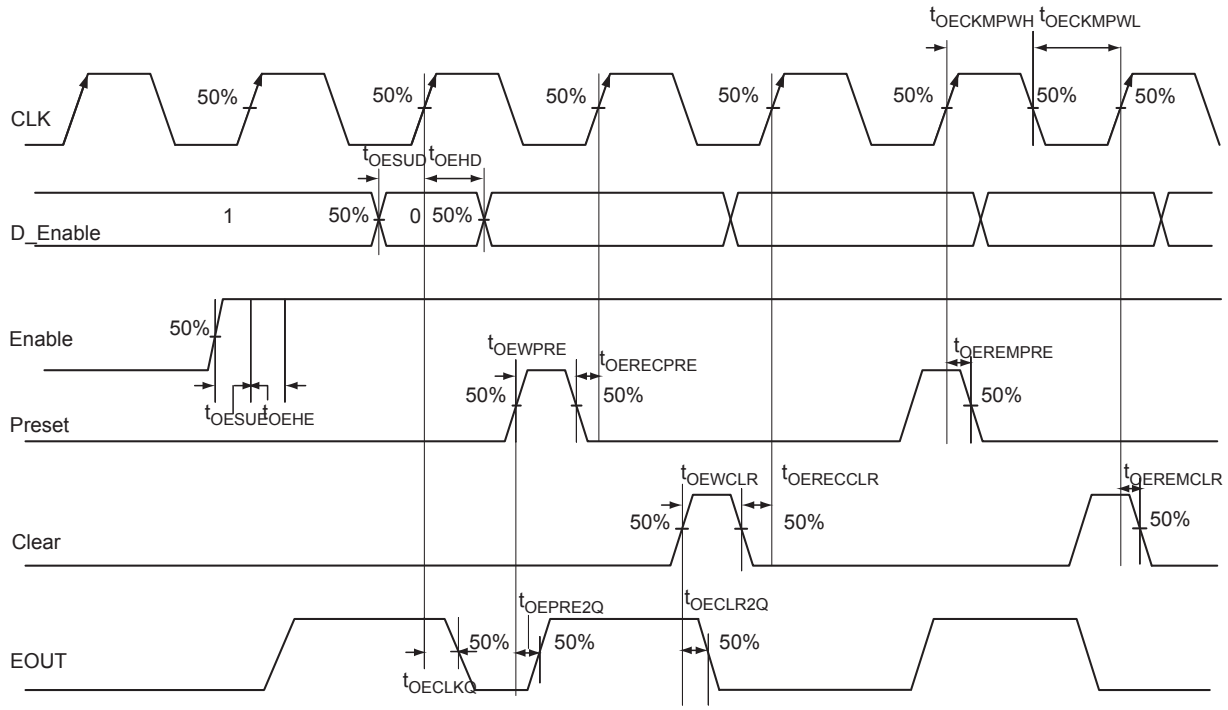


Figure 2-29 • **Output Enable Register Timing Diagram**

Timing Characteristics

Table 2-88 • **Output Enable Register Propagation Delays**
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Parameter	Description	–2	–1	Std.	Units
t_{OECLKQ}	Clock-to-Q of the Output Enable Register	0.59	0.67	0.79	ns
t_{OESUD}	Data Setup Time for the Output Enable Register	0.31	0.36	0.42	ns
t_{OEHD}	Data Hold Time for the Output Enable Register	0.00	0.00	0.00	ns
t_{OESUE}	Enable Setup Time for the Output Enable Register	0.44	0.50	0.58	ns
t_{OEHE}	Enable Hold Time for the Output Enable Register	0.00	0.00	0.00	ns
$t_{OECLR2Q}$	Asynchronous Clear-to-Q of the Output Enable Register	0.67	0.76	0.89	ns
$t_{OEPRE2Q}$	Asynchronous Preset-to-Q of the Output Enable Register	0.67	0.76	0.89	ns
$t_{OEREMCLR}$	Asynchronous Clear Removal Time for the Output Enable Register	0.00	0.00	0.00	ns
$t_{ORECCLR}$	Asynchronous Clear Recovery Time for the Output Enable Register	0.22	0.25	0.30	ns
$t_{OEREMPRE}$	Asynchronous Preset Removal Time for the Output Enable Register	0.00	0.00	0.00	ns
$t_{ORECPRE}$	Asynchronous Preset Recovery Time for the Output Enable Register	0.22	0.25	0.30	ns
t_{OEWCLR}	Asynchronous Clear Minimum Pulse Width for the Output Enable Register	0.22	0.25	0.30	ns
t_{OEWPRE}	Asynchronous Preset Minimum Pulse Width for the Output Enable Register	0.22	0.25	0.30	ns
$t_{OECKMPWH}$	Clock Minimum Pulse Width High for the Output Enable Register	0.36	0.41	0.48	ns
$t_{OECKMPWL}$	Clock Minimum Pulse Width Low for the Output Enable Register	0.32	0.37	0.43	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

Timing Characteristics

Table 2-93 • Combinatorial Cell Propagation Delays
Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V

Combinatorial Cell	Equation	Parameter	–2	–1	Std.	Units
INV	Y = !A	t_{PD}	0.40	0.46	0.54	ns
AND2	Y = A · B	t_{PD}	0.47	0.54	0.63	ns
NAND2	Y = !(A · B)	t_{PD}	0.47	0.54	0.63	ns
OR2	Y = A + B	t_{PD}	0.49	0.55	0.65	ns
NOR2	Y = !(A + B)	t_{PD}	0.49	0.55	0.65	ns
XOR2	Y = A ⊕ B	t_{PD}	0.74	0.84	0.99	ns
MAJ3	Y = MAJ(A , B, C)	t_{PD}	0.70	0.79	0.93	ns
XOR3	Y = A ⊕ B ⊕ C	t_{PD}	0.87	1.00	1.17	ns
MUX2	Y = A !S + B S	t_{PD}	0.51	0.58	0.68	ns
AND3	Y = A · B · C	t_{PD}	0.56	0.64	0.75	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-5 for derating values.

VersaTile Specifications as a Sequential Module

The ProASIC3E library offers a wide variety of sequential cells, including flip-flops and latches. Each has a data input and optional enable, clear, or preset. In this section, timing characteristics are presented for a representative sample from the library. For more details, refer to the *Fusion, IGLOO/e, and ProASIC3/E Macro Library Guide*.

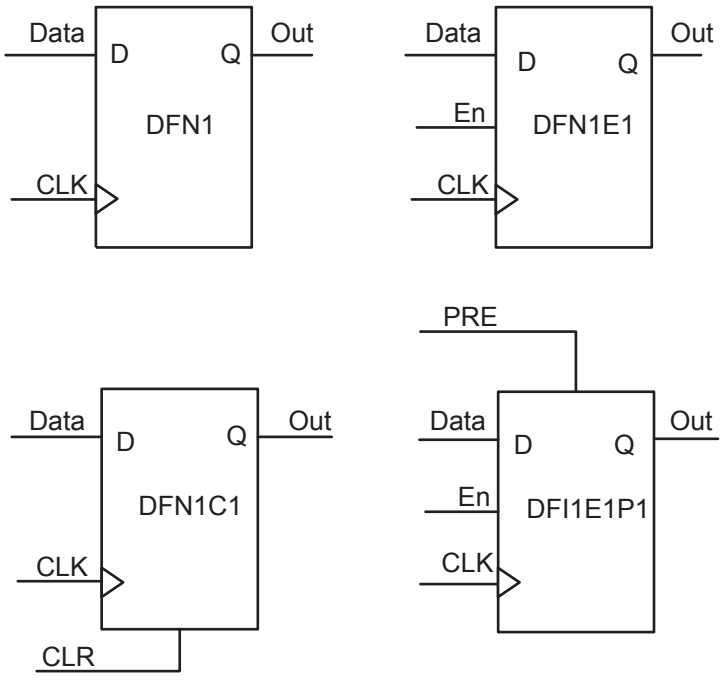
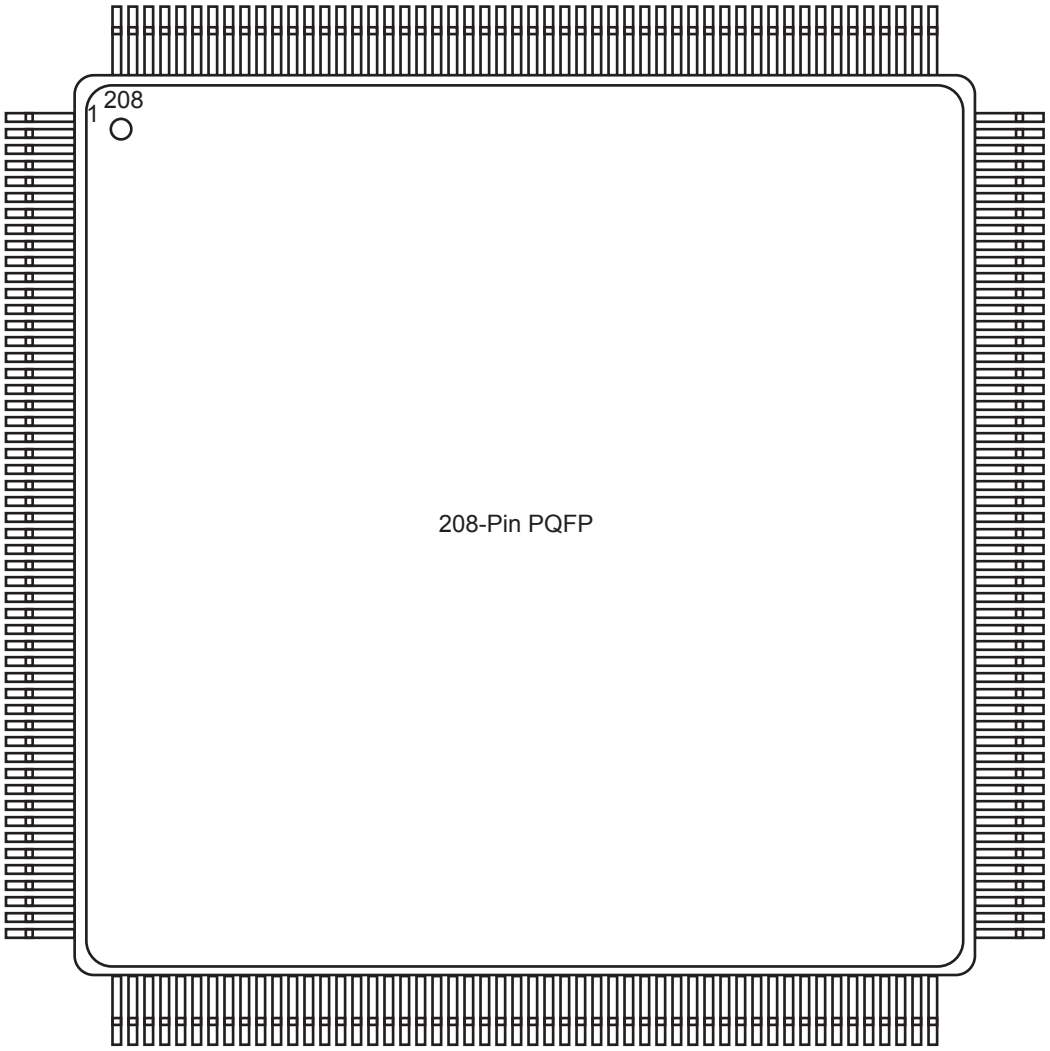


Figure 2-36 • Sample of Sequential Cells

4 – Package Pin Assignments

PQ208



Note: This is the top view of the package.

Note

For Package Manufacturing and Environmental information, visit the Resource Center at *http://www.microsemi.com/products/fpga-soc/solutions*.

FG256	
Pin Number	**A3PE600 Function**
G13	GCC1/IO50PPB2V1
G14	IO44NDB2V1
G15	IO44PDB2V1
G16	IO49NSB2V1
H1	GFB0/IO119NPB7V0
H2	GFA0/IO118NDB6V1
H3	GFB1/IO119PPB7V0
H4	VCOMPLF
H5	GFC0/IO120NPB7V0
H6	VCC
H7	GND
H8	GND
H9	GND
H10	GND
H11	VCC
H12	GCC0/IO50NPB2V1
H13	GCB1/IO51PPB2V1
H14	GCA0/IO52NPB3V0
H15	VCOMPLC
H16	GCB0/IO51NPB2V1
J1	GFA2/IO117PSB6V1
J2	GFA1/IO118PDB6V1
J3	VCCPLF
J4	IO116NDB6V1
J5	GFB2/IO116PDB6V1
J6	VCC
J7	GND
J8	GND
J9	GND
J10	GND
J11	VCC
J12	GCB2/IO54PPB3V0
J13	GCA1/IO52PPB3V0
J14	GCC2/IO55PPB3V0
J15	VCCPLC
J16	GCA2/IO53PSB3V0

FG256	
Pin Number	**A3PE600 Function**
K1	GFC2/IO115PSB6V1
K2	IO113PPB6V1
K3	IO112PDB6V1
K4	IO112NDB6V1
K5	VCCIB6
K6	VCC
K7	GND
K8	GND
K9	GND
K10	GND
K11	VCC
K12	VCCIB3
K13	IO54NPB3V0
K14	IO57NPB3V0
K15	IO55NPB3V0
K16	IO57PPB3V0
L1	IO113NPB6V1
L2	IO109PPB6V0
L3	IO108PDB6V0
L4	IO108NDB6V0
L5	VCCIB6
L6	GND
L7	VCC
L8	VCC
L9	VCC
L10	VCC
L11	GND
L12	VCCIB3
L13	GDB0/IO66NPB3V1
L14	IO60NDB3V1
L15	IO60PDB3V1
L16	IO61PDB3V1
M1	IO109NPB6V0
M2	IO106NDB6V0
M3	IO106PDB6V0
M4	GEC0/IO104NPB6V0

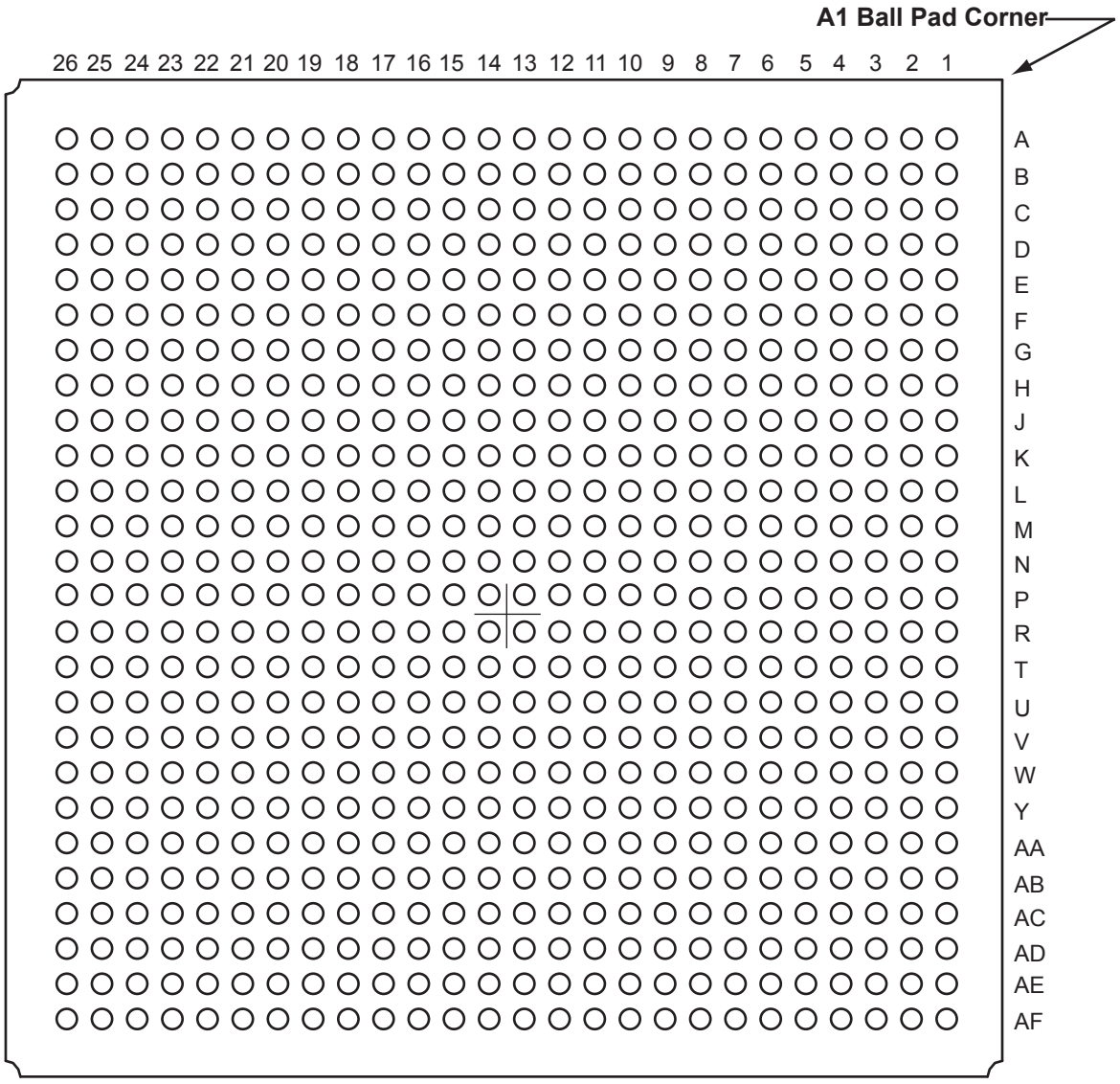
FG256	
Pin Number	**A3PE600 Function**
M5	VMV5
M6	VCCIB5
M7	VCCIB5
M8	IO84NDB5V0
M9	IO84PDB5V0
M10	VCCIB4
M11	VCCIB4
M12	VMV3
M13	VCCPLD
M14	GDB1/IO66PPB3V1
M15	GDC1/IO65PDB3V1
M16	IO61NDB3V1
N1	IO105PDB6V0
N2	IO105NDB6V0
N3	GEC1/IO104PPB6V0
N4	VCOMPLE
N5	GNDQ
N6	GEA2/IO101PPB5V2
N7	IO92NDB5V1
N8	IO90NDB5V1
N9	IO82NDB5V0
N10	IO74NDB4V1
N11	IO74PDB4V1
N12	GNDQ
N13	VCOMPLD
N14	VJTAG
N15	GDC0/IO65NDB3V1
N16	GDA1/IO67PDB3V1
P1	GEB1/IO103PDB6V0
P2	GEB0/IO103NDB6V0
P3	VMV6
P4	VCCPLE
P5	IO101NPB5V2
P6	IO95PPB5V1
P7	IO92PDB5V1
P8	IO90PDB5V1

FG324	
Pin Number	A3PE3000 FBGA
A1	GND
A2	IO08NDB0V0
A3	IO08PDB0V0
A4	IO10NDB0V1
A5	IO10PDB0V1
A6	IO12PDB0V1
A7	GND
A8	IO32NDB0V3
A9	IO32PDB0V3
A10	IO42PPB1V0
A11	IO52NPB1V1
A12	GND
A13	IO66NDB1V3
A14	IO72NDB1V3
A15	IO72PDB1V3
A16	IO74NDB1V4
A17	IO74PDB1V4
A18	GND
B1	IO305PDB7V3
B2	GAB2/IO308PDB7V4
B3	GAA0/IO00NPB0V0
B4	VCCIB0
B5	GNDQ
B6	IO12NDB0V1
B7	IO18NDB0V2
B8	VCCIB0
B9	IO42NPB1V0
B10	IO44NDB1V0
B11	VCCIB1
B12	IO52PPB1V1
B13	IO66PDB1V3
B14	GNDQ
B15	VCCIB1
B16	GBA0/IO81NDB1V4
B17	GBA1/IO81PDB1V4
B18	IO88PDB2V0

FG324	
Pin Number	A3PE3000 FBGA
C1	IO305NDB7V3
C2	IO308NDB7V4
C3	GAA2/IO309PPB7V4
C4	GAA1/IO00PPB0V0
C5	VMV0
C6	IO14NDB0V1
C7	IO18PDB0V2
C8	IO40NDB0V4
C9	IO40PDB0V4
C10	IO44PDB1V0
C11	IO56NDB1V1
C12	IO64NDB1V2
C13	IO64PDB1V2
C14	VMV1
C15	GBC0/IO79NDB1V4
C16	GBC1/IO79PDB1V4
C17	GBB2/IO83PPB2V0
C18	IO88NDB2V0
D1	IO303PDB7V3
D2	VCCIB7
D3	GAC2/IO307PPB7V4
D4	IO309NPB7V4
D5	GAB1/IO01PPB0V0
D6	IO14PDB0V1
D7	IO24NDB0V2
D8	IO24PDB0V2
D9	IO28PDB0V3
D10	IO48NDB1V0
D11	IO56PDB1V1
D12	IO60PPB1V2
D13	GBB0/IO80NDB1V4
D14	GBB1/IO80PDB1V4
D15	GBA2/IO82PDB2V0
D16	IO83NPB2V0
D17	VCCIB2
D18	IO90PDB2V1

FG324	
Pin Number	A3PE3000 FBGA
E1	IO303NDB7V3
E2	GNDQ
E3	VMV7
E4	IO307NPB7V4
E5	VCCPLA
E6	GAB0/IO01NPB0V0
E7	VCCIB0
E8	GND
E9	IO28NDB0V3
E10	IO48PDB1V0
E11	GND
E12	VCCIB1
E13	IO60NPB1V2
E14	VCCPLB
E15	IO82NDB2V0
E16	VMV2
E17	GNDQ
E18	IO90NDB2V1
F1	IO299NDB7V3
F2	IO299PDB7V3
F3	IO295PDB7V2
F4	IO295NDB7V2
F5	VCOMPLA
F6	IO291PPB7V2
F7	GAC0/IO02NDB0V0
F8	GAC1/IO02PDB0V0
F9	IO26PDB0V3
F10	IO34PDB0V4
F11	IO58NDB1V2
F12	IO58PDB1V2
F13	IO94PPB2V1
F14	VCOMPLB
F15	GBC2/IO84PDB2V0
F16	IO84NDB2V0
F17	IO92NDB2V1
F18	IO92PDB2V1

FG676



Note: This is the bottom view of the package.

Note

For Package Manufacturing and Environmental information, visit the Resource Center at *http://www.microsemi.com/products/fpga-soc/solutions*.

FG676	
Pin Number	A3PE1500 Function
R21	IO89NDB3V0
R22	GCB2/IO89PDB3V0
R23	IO90NDB3V0
R24	GCC2/IO90PDB3V0
R25	IO91PDB3V0
R26	IO91NDB3V0
T1	IO186PDB6V2
T2	IO185NDB6V2
T3	GNDQ
T4	IO180PDB6V1
T5	IO180NDB6V1
T6	IO188NDB6V2
T7	GFB2/IO188PDB6V2
T8	VCCIB6
T9	VCC
T10	GND
T11	GND
T12	GND
T13	GND
T14	GND
T15	GND
T16	GND
T17	GND
T18	VCC
T19	VCCIB3
T20	IO99PDB3V1
T21	IO99NDB3V1
T22	IO97PDB3V1
T23	IO97NDB3V1
T24	GNDQ
T25	IO93PPB3V0
T26	NC
U1	IO186NDB6V2
U2	IO184NDB6V2
U3	IO184PDB6V2
U4	IO182NDB6V1

FG676	
Pin Number	A3PE1500 Function
U5	IO182PDB6V1
U6	IO178PDB6V1
U7	IO178NDB6V1
U8	VCCIB6
U9	VCC
U10	GND
U11	GND
U12	GND
U13	GND
U14	GND
U15	GND
U16	GND
U17	GND
U18	VCC
U19	VCCIB3
U20	NC
U21	IO101NDB3V1
U22	IO101PDB3V1
U23	IO92NDB3V0
U24	IO92PDB3V0
U25	IO95PDB3V1
U26	IO93NPB3V0
V1	IO183PDB6V2
V2	IO183NDB6V2
V3	VMV6
V4	IO181PDB6V1
V5	IO181NDB6V1
V6	IO176PDB6V1
V7	IO176NDB6V1
V8	VCCIB6
V9	VCC
V10	VCC
V11	VCC
V12	VCC
V13	VCC
V14	VCC

FG676	
Pin Number	A3PE1500 Function
V15	VCC
V16	VCC
V17	VCC
V18	VCC
V19	VCCIB3
V20	IO107PDB3V2
V21	IO107NDB3V2
V22	IO103NDB3V2
V23	IO103PDB3V2
V24	VMV3
V25	IO95NDB3V1
V26	IO94PDB3V0
W1	IO179NDB6V1
W2	IO179PDB6V1
W3	IO177NDB6V1
W4	IO177PDB6V1
W5	IO172PDB6V0
W6	IO172NDB6V0
W7	VCC
W8	VCC
W9	VCCIB5
W10	VCCIB5
W11	VCCIB5
W12	VCCIB5
W13	VCCIB5
W14	VCCIB4
W15	VCCIB4
W16	VCCIB4
W17	VCCIB4
W18	VCCIB4
W19	VCC
W20	VCCIB3
W21	GDB0/IO109NDB3V2
W22	GDB1/IO109PDB3V2
W23	IO105NDB3V2
W24	IO105PDB3V2

FG896	
Pin Number	A3PE3000 Function
T11	VCC
T12	GND
T13	GND
T14	GND
T15	GND
T16	GND
T17	GND
T18	GND
T19	GND
T20	VCC
T21	VCCIB3
T22	IO109NPB2V3
T23	IO116NDB3V0
T24	IO118NDB3V0
T25	IO122NPB3V1
T26	GCA1/IO114PPB3V0
T27	GCB0/IO113NPB2V3
T28	GCA2/IO115PPB3V0
T29	VCCPLC
T30	IO121PDB3V0
U1	IO268PDB6V4
U2	IO264NDB6V3
U3	IO264PDB6V3
U4	IO258PDB6V3
U5	IO258NDB6V3
U6	IO257PPB6V2
U7	IO261PPB6V3
U8	IO265NDB6V3
U9	IO263NDB6V3
U10	VCCIB6
U11	VCC
U12	GND
U13	GND
U14	GND
U15	GND
U16	GND

FG896	
Pin Number	A3PE3000 Function
U17	GND
U18	GND
U19	GND
U20	VCC
U21	VCCIB3
U22	IO120PDB3V0
U23	IO128PDB3V1
U24	IO124PDB3V1
U25	IO124NDB3V1
U26	IO126PDB3V1
U27	IO129PDB3V1
U28	IO127PDB3V1
U29	IO125PDB3V1
U30	IO121NDB3V0
V1	IO268NDB6V4
V2	IO262PDB6V3
V3	IO260PDB6V3
V4	IO252PDB6V2
V5	IO257NPB6V2
V6	IO261NPB6V3
V7	IO255PDB6V2
V8	IO259PDB6V3
V9	IO259NDB6V3
V10	VCCIB6
V11	VCC
V12	GND
V13	GND
V14	GND
V15	GND
V16	GND
V17	GND
V18	GND
V19	GND
V20	VCC
V21	VCCIB3
V22	IO120NDB3V0

FG896	
Pin Number	A3PE3000 Function
V23	IO128NDB3V1
V24	IO132PDB3V2
V25	IO130PPB3V2
V26	IO126NDB3V1
V27	IO129NDB3V1
V28	IO127NDB3V1
V29	IO125NDB3V1
V30	IO123PDB3V1
W1	IO266NDB6V4
W2	IO262NDB6V3
W3	IO260NDB6V3
W4	IO252NDB6V2
W5	IO251NDB6V2
W6	IO251PDB6V2
W7	IO255NDB6V2
W8	IO249PPB6V1
W9	IO253PDB6V2
W10	VCCIB6
W11	VCC
W12	GND
W13	GND
W14	GND
W15	GND
W16	GND
W17	GND
W18	GND
W19	GND
W20	VCC
W21	VCCIB3
W22	IO134PDB3V2
W23	IO138PDB3V3
W24	IO132NDB3V2
W25	IO136NPB3V2
W26	IO130NPB3V2
W27	IO141PDB3V3
W28	IO135PDB3V2

Revision	Changes	Page
Revision 9 (Aug 2009) Product Brief v1.2	All references to speed grade –F have been removed from this document.	N/A
	The "Pro I/Os with Advanced I/O Standards" section was revised to add definitions of hot-swap and cold-sparing.	1-6
DC and Switching Characteristics v1.3	3.3 V LVCMOS and 1.2 V LVCMOS Wide Range support was added to the datasheet. This affects all tables that contained 3.3 V LVCMOS and 1.2 V LVCMOS data.	N/A
	IIL and IIH input leakage current information was added to all "Minimum and Maximum DC Input and Output Levels" tables.	N/A
	–F was removed from the datasheet. The speed grade is no longer supported.	N/A
	In the Table 2-2 • Recommended Operating Conditions [1] "3.0 V DC supply voltage" and note 4 are new.	2-2
	The Table 2-4 • Overshoot and Undershoot Limits [1] table was updated.	2-3
	The Table 2-6 • Temperature and Voltage Derating Factors for Timing Delays table was updated.	2-5
	There are new parameters and data was updated in the Table 2-99 • RAM4K9 table.	2-76
	There are new parameters and data was updated in the Table 2-100 • RAM512X18 table.	2-77
Revision 8 (Feb 2008) Product Brief v1.1	Table 1-2 • ProASIC3E FPGAs Package Sizes Dimensions is new.	1-II
Revision 7 (Jun 2008) DC and Switching Characteristics v1.2	The title of Table 2-4 • Overshoot and Undershoot Limits [1] was modified to remove "as measured on quiet I/Os." Table note 2 was revised to remove "estimated SSO density over cycles." Table note 3 was deleted.	2-3
	Table 2-78 • LVDS Minimum and Maximum DC Input and Output Levels was updated.	2-50
Revision 6 (Jun 2008)	The A3PE600 "FG484" table was missing G22. The pin and its function were added to the table.	4-27
Revision 5 (Jun 2008) Packaging v1.4	The naming conventions changed for the following pins in the "FG484" for the A3PE600: **Pin Number** — **New Function Name** J19 — IO45PPB2V1 K20 — IO45NPB2V1 M2 — IO114NPB6V1 N1 — IO114PPB6V1 N4 — GFC2/IO115PPB6V1 P3 — IO115NPB6V1	4-22
Revision 4 (Apr 2008) Product Brief v1.0	The product brief portion of the datasheet was divided into two sections and given a version number, starting at v1.0. The first section of the document includes features, benefits, ordering information, and temperature and speed grade offerings. The second section is a device family overview.	N/A
Packaging v1.3	The "FG324" package diagram was replaced.	4-12

Revision	Changes	Page
v2.1 (continued)	The words "ambient temperature" were added to the temperature range in the "Temperature Grade Offerings", "Speed Grade and Temperature Grade Matrix", and "Speed Grade and Temperature Grade Matrix" sections.	1-I
	The "Clock Conditioning Circuit (CCC) and PLL" section was updated.	1-I
	The caption "Main (chip)" in Figure 2-9 • Overview of Automotive ProASIC3 VersaNet Global Network was changed to "Chip (main)."	2-9
	The T_J parameter in Table 3-2 • Recommended Operating Conditions was changed to T_A, ambient temperature, and table notes 4–6 were added.	3-2
	The "PLL Macro" section was updated to add information on the VCO and PLL outputs during power-up.	2-15
v2.0 (April 2007)	In the "Temperature Grade Offerings" section, Ambient was deleted.	iii
	Ambient was deleted from "Temperature Grade Offerings".	iii
	Ambient was deleted from the "Speed Grade and Temperature Grade Matrix".	iv
	The "PLL Macro" section was updated to include power-up information.	2-15
	Table 2-13 • ProASIC3E CCC/PLL Specification was updated.	2-30
	Figure 2-19 • Peak-to-Peak Jitter Definition is new.	2-18
	The "SRAM and FIFO" section was updated with operation and timing requirement information.	2-21
	The "RESET" section was updated with read and write information.	2-25
	The "RESET" section was updated with read and write information.	2-25
	The "Introduction" in the "Advanced I/Os" section was updated to include information on input and output buffers being disabled.	2-28
	In the Table 2-15 • Levels of Hot-Swap Support, the ProASIC3 compliance descriptions were updated for levels 3 and 4.	2-34
	Table 2-45 • I/O Hot-Swap and 5 V Input Tolerance Capabilities in ProASIC3E Devices was updated.	2-64
	Notes 3, 4, and 5 were added to Table 2-17 • Comparison Table for 5 V–Compliant Receiver Scheme. 5 x 52.72 was changed to 52.7 and the Maximum current was updated from 4 x 52.7 to 5 x 52.7.	2-40
	The "VCCPLF PLL Supply Voltage" section was updated.	2-50
	The "VPUMP Programming Supply Voltage" section was updated.	2-50
	The "GL Globals" section was updated to include information about direct input into quadrant clocks.	2-51
	VJTAG was deleted from the "TCK Test Clock" section.	2-51
	In Table 2-22 • Recommended Tie-Off Values for the TCK and TRST Pins, TSK was changed to TCK in note 2. Note 3 was also updated.	2-51
	Ambient was deleted from Table 3-2 • Recommended Operating Conditions. VPUMP programming mode was changed from "3.0 to 3.6" to "3.15 to 3.45".	3-2
	Note 3 is new in Table 3-4 • Overshoot and Undershoot Limits (as measured on quiet I/Os).	3-2
	In EQ 3-2, 150 was changed to 110 and the result changed to 5.88.	3-5

Revision	Changes	Page
Advance v0.5 (continued)	The "I/O User Input/Output" pin description was updated to include information on what happens when the pin is unused.	2-50
	The "JTAG Pins" section was updated to include information on what happens when the pin is unused.	2-51
	The "Programming" section was updated to include information concerning serialization.	2-53
	The "JTAG 1532" section was updated to include SAMPLE/PRELOAD information.	2-54
	The "DC and Switching Characteristics" chapter was updated with new information.	Starting on page 3-1
	Table 3-6 was updated.	3-5
	In Table 3-10, PAC4 was updated.	3-8
	Table 3-19 was updated.	3-20
	The note in Table 3-24 was updated.	3-23
	All Timing Characteristics tables were updated from LVTTL to Register Delays	3-26 to 3-64
	The Timing Characteristics for RAM4K9, RAM512X18, and FIFO were updated.	3-74 to 3-79
	F_{TCKMAX} was updated in Table 3-98.	3-80
Advance v0.4 (October 2005)	The "Packaging Tables" table was updated.	ii
Advance v0.3	Figure 2-11 was updated.	2-9
	The "Clock Resources (VersaNets)" section was updated.	2-9
	The "VersaNet Global Networks and Spine Access" section was updated.	2-9
	The "PLL Macro" section was updated.	2-15
	Figure 2-27 was updated.	2-28
	Figure 2-20 was updated.	2-19
	Table 2-5 was updated.	2-25
	Table 2-6 was updated.	2-25
	The "FIFO Flag Usage Considerations" section was updated.	2-27
	Table 2-33 was updated.	2-51
	Figure 2-24 was updated.	2-31
	The "Cold-Sparing Support" section is new.	2-34
	Table 2-45 was updated.	2-64
	Table 2-48 was updated.	2-81
	Pin descriptions in the "JTAG Pins" section were updated.	2-51
	The "Pin Descriptions" section was updated.	2-50
	Table 3-7 was updated.	3-6